The MRFIC Line 1.8 GHz LNA/Downmixer

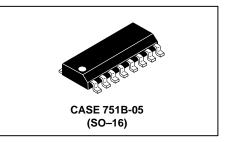
Designed primarily for use in DECT, Japan Personal Handy Phone (JPHP), and other wireless Personal Communication Systems (PCS) applications. The MRFIC1804 includes a low noise amplifier and downmixer in a low-cost SOIC-16 package. The integrated circuit requires minimal off-chip matching while allowing for the maximum in flexibility and efficiency. The mixer is optimized for low side injection and offers reasonable intercept point as well as high efficiency and 4 dB of conversion gain. Image filtering is implemented off-chip to allow maximum flexibility. With both TX and RX enable pins low, the device is in standby mode and draws less than 0.5 mA.

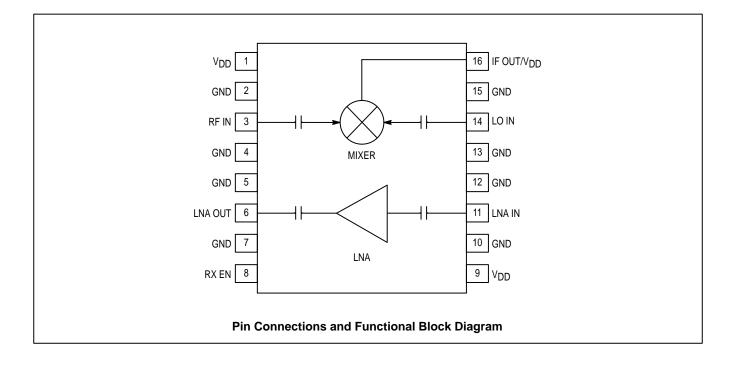
Together with the rest of the MRFIC180X series, this GaAs IC family offers the complete transmit and receive functions, less LO and filters, needed for a typical 1.8 GHz cordless telephone.

- Usable Frequency Range = 1.5 to 2.2 GHz
- 14 dB Gain, 2.3 dB Noise Figure LNA
- 4 dB Gain, 13 dB Noise Figure Mixer
- 0.9 dB Mixer Input Intercept Point
- Simple LO/IF Off-Chip Matching for Maximum Flexibility
- Low Power Consumption = 24 mW (Typ)
- Single Bias Supply = 2.7 to 3.3 V
- Low LO Power Requirement = 5 dBm (Typ)
- Low Cost Surface Mount Plastic Package
- Available in Tape and Reel by Adding R2 Suffix to Part Number. R2 Suffix = 2,500 Units per 16 mm, 13 inch Reel.
- Device Marking = M1804



1.8 GHz LOW NOISE AMPLIFIER AND DOWNMIXER GaAs MONOLITHIC INTEGRATED CIRCUIT







MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

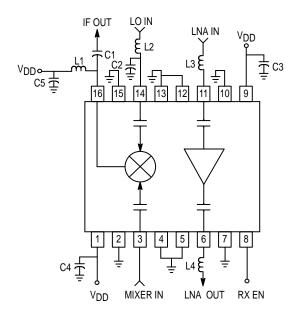
Rating	Symbol	Limit	Unit
Supply Voltage	V _{DD}	5	Vdc
LNA Input Power (Standby Mode)	LNA _{in}	10	dBm
LO Input Power	PLO	0	dBm
Receive Enable Voltage	RX EN	5	Vdc
Storage Temperature Range	T _{stg}	– 65 to +150	°C
Operating Ambient Temperature	Τ _Α	– 30 to +85	°C

RECOMMENDED OPERATING RANGES

Parameter	Symbol	Value	Unit
RF Input Frequency	^f RF	1.8 to 1.925	GHz
Mixer LO Frequency	fLO	1.5 to 1.9	GHz
IF Output Frequency	fIF	70 to 325	MHz
Supply Voltage	V _{DD}	2.7 to 3.3	Vdc
Receive Enable Voltage	RX EN	2.7 to 3.3	Vdc

$\textbf{ELECTRICAL CHARACTERISTICS} (V_{DD} = 3 \text{ V}, \text{ } \text{T}_{A} = 25^{\circ}\text{C}, \text{ } \text{LO} = 1790 \text{ } \text{MHz} @ - 5 \text{ } \text{dBm}, \text{ } \text{RF} = 1.9 \text{ } \text{GHz} \text{ }, \text{ } \text{RX EN} = 3 \text{ } \text{V})$

Characteristic	Min	Тур	Max	Unit
LNA Gain	—	14	—	dB
LNA Noise Figure	—	2.3	—	dB
LNA Input 3rd Order Intercept	—	-11	—	dBm
Mixer Conversion Gain (into 50 Ω)	—	4	—	dB
Mixer Noise Figure	—	13	—	dB
Mixer Input 3rd Order Intercept	—	0.9	—	dBm
Downconverter Gain (Less Image Filter Loss)	16	—	—	dB
Supply Current, RX Mode (RX EN = 3 V, LO _{off})	—	7	10	mA
Standby Mode Current (RX EN = 0 V, LO off)	_	_	0.5	mA



- C1 12 pF (110 MHz) or 7.5 pF (240 MHz)
- 0.8 pF 100 pF C2
- C3, C4 C5 1000 pF
 - 82 nH (110 MHz) or 15 nH (240 MHz)
- L1 L2 8.2 nH
- 3.0 nH (Microstrip) L3, L4



	\$11		\$ ₂₁		\$ ₁₂		\$ ₂₂	
Freq (GHz)	Mag	Angle	Mag	Angle	Mag	Angle	Mag	Angle
1.5	0.801	-64.71	5.65	-63.77	0.025	139.08	0.685	-62.55
1.6	0.741	-70.03	6.07	-80.96	0.033	128.21	0.622	-74.44
1.7	0.641	-73.54	6.63	-98.00	0.038	123.07	0.622	-83.36
1.8	0.559	-72.72	6.70	-113.87	0.047	113.17	0.560	-92.40
1.82	0.533	-71.10	6.58	-117.42	0.046	111.66	0.543	-93.20
1.84	0.512	-71.20	6.32	-120.25	0.046	109.36	0.530	-94.40
1.86	0.494	-69.93	5.92	-123.27	0.049	107.72	0.513	-95.19
1.88	0.478	-68.86	5.79	-126.51	0.052	106.52	0.498	-95.56
1.9	0.467	-67.50	5.88	-129.49	0.054	104.49	0.486	-96.35
1.92	0.452	-66.18	5.98	-132.33	0.055	103.55	0.476	-97.14
2.0	0.383	-57.10	5.57	-143.54	0.055	97.41	0.412	-96.10
2.1	0.326	-47.69	5.06	-155.69	0.058	92.26	0.344	-90.55
2.2	0.271	-35.10	4.61	-167.78	0.063	86.81	0.276	-83.89
2.3	0.205	-15.07	4.12	175.72	0.072	83.78	0.192	-63.78
2.4	0.708	-12.53	1.84	-155.83	0.073	45.03	0.406	-48.22
2.5	0.462	-34.07	3.18	-178.63	0.055	58.37	0.292	-66.60

Table 1. LNA S-Parameters

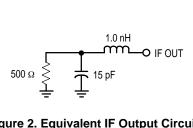
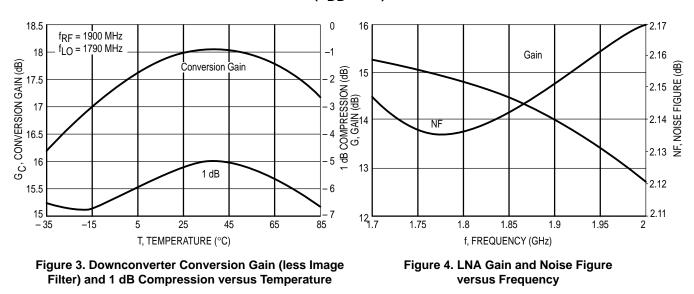
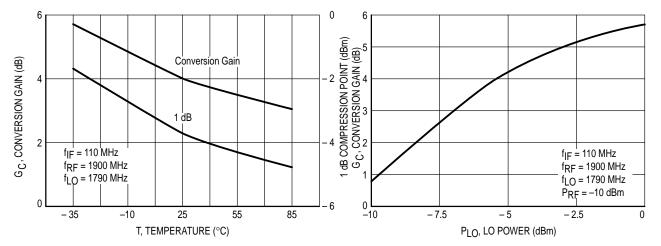
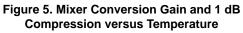


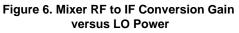
Figure 2. Equivalent IF Output Circuit

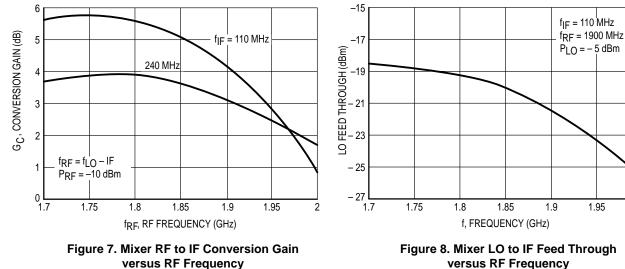
TYPICAL CHARACTERISTICS $(V_{DD} = 3 V)$











1.95

2

DESIGN AND APPLICATIONS INFORMATION

The MRFIC1804 consists of a two-stage GaAs MESFET low noise amplifier and a single ended MESFET mixer. The LNA design conserves bias current through stacking of the two FETs, thus reusing the current. The mixer consists of a common gate stage driving a common source stage with the IF output being the drain of the common source stage shunted with 15 pF. The LNA output and mixer input have been separated to allow the addition of an external image filter. Such a filter, usually ceramic, is useful in improving the mixer noise figure and third order intercept performance. It also provides LO rejection to reduce the amount of LO power which may leak to the antenna. Alternatively, image trapping can be implemented at the LNA input or output with discrete or distributed components.

The design has been optimized for application in the PCS bands around 1.9 GHz but is usable from around 1.5 GHz to 2.2 GHz. For applications at 1.9 GHz and IFs of 110 MHz or 240 MHz, the circuit shown in Figure 1 can be used. This circuit was used to derive the characterization data shown in Figures 3 through 8. For other IF frequencies in the 100

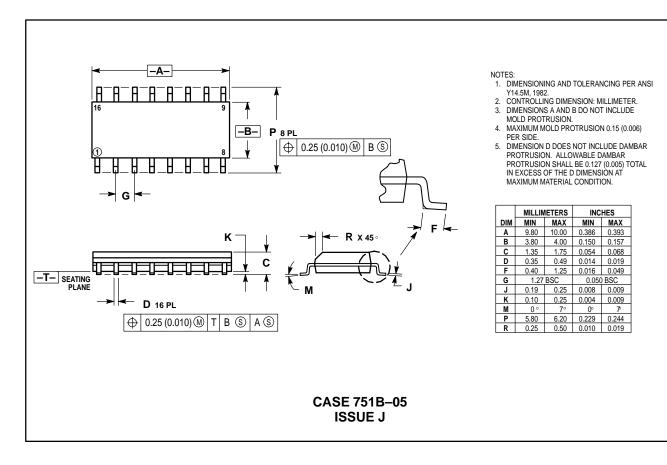
MHz to 350 MHz range, use the IF equivalent circuit shown in Figure 2 for matching network design. As can be seen in the characterization curves, performance appears to degrade above about 1.85 GHz. This is partially a function of the circuit shown in Figure 1 and can be improved, first, by adjusting the LO input match, second, by matching LNA input and and the mixer input off chip.

As with all RF circuits, layout is important. Ground vias must be close to the component or lead to be grounded and vias must be plentiful. RF signal lines should be controlled impedance such as microstrip. Bypassing of power supply leads as shown in Figure 1 is essential to avoid oscillation of the circuits.

EVALUATION BOARDS

Evaluation boards are available for RF Monolithic Integrated Circuits by adding a "TF" suffix to the device type. For a complete list of currently available boards and ones in development for newly introduced poduct, please contact your local Motorola Distributor or Sales Office.

PACKAGE DIMENSIONS



Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters can and do vary in different applications. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death Motorola was negligent regarding the design or manufacture of the part. Motorola and (**A**) are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employee.

How to reach us:

USA/EUROPE: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447 JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, Toshikatsu Otsuki, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–3521–8315

MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE (602) 244-6609 INTERNET: http://Design-NET.com

🕅 MOTOROLA

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

